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(54) Title: SPIN TORQUE TRANSFER MEMORY CELL STRUCTURES AND METHODS

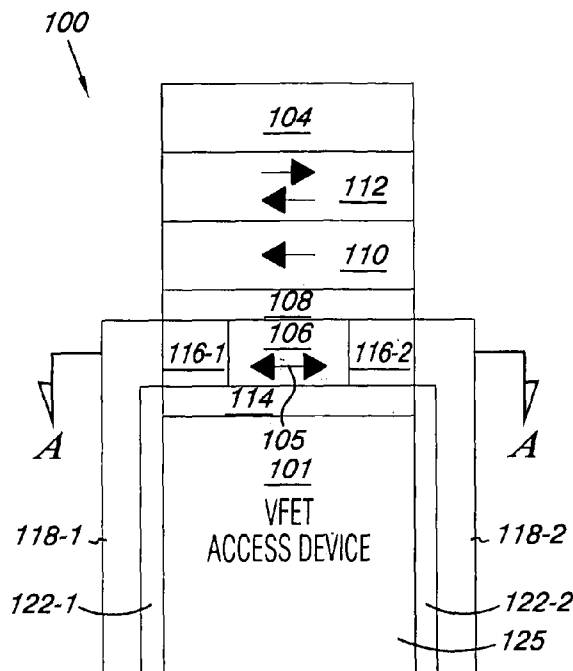


Fig. 1A

(57) Abstract: Spin Torque Transfer (STT) memory cell structures and methods are described herein. One or more STT memory cell structures comprise a STT stack including: a pinned ferromagnetic material in contact with an anti-ferromagnetic material; a tunneling barrier material positioned between a ferromagnetic storage material and the pinned ferromagnetic material; a multiferroic material in contact with the ferromagnetic storage material; and a first electrode and a second electrode, wherein the anti-ferromagnetic material, the pinned ferromagnetic material, and the ferromagnetic storage material are located between the first electrode and the second electrode. The STT memory cell structure can include a third electrode and a fourth electrode, wherein at least a first portion of the multiferroic material is located between the third and the fourth electrode.



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B. FIELDS SEARCHED

Minimum documentation searched (classification system followed by classification symbols)

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Documentation searched other than minimum documentation to the extent that such documents are included in the fields searched

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eKOMPASS(KIPO internal) & Keywords: spin torque transfer, STT, memory cell, multiferroic, ferroic magnetic, antiferroic magnetic

C. DOCUMENTS CONSIDERED TO BE RELEVANT

Category*	Citation of document, with indication, where appropriate, of the relevant passages	Relevant to claim No.
A	WO 2010-032574 A1 (HITACHI, LTD.) 25 March 2010 See figures 1-4; paragraphs [15]-[20],[22],[24] and [26]-[28]	1-51
A	JP 2010-098259 A (INSTITUTE OF PHYSICAL & CHEMICAL RESEARCH) 30 April 2010 See figure 1; paragraphs [28]-[31],[46]-[51]	1-51
A	WO 2010-039424 A1 (MICRON TECHNOLOGY, INC.) 08 April 2010 See figures 3,5 and paragraphs [28]-[33],[37]-[39]	1-51
A	US 2010-0193888 A1 (GU, SHIQUN et al.) 05 August 2010 See figures 4-6; paragraphs [35]-[39]; claim 1	1-51
A	US 2010-0220516 A1 (LEE, KANGHO et al.) 02 September 2010 See figure 2; paragraphs [6],[24]-[28]	1-51
A	KR 10-0866973 B1 (EWA WOMAN'S UNIVERSITY RESEARCH AND BUSINESS CENTER) 05 November 2008 See figure 2; paragraphs [61]-[70]; claim 1	1-51
A	US 2005-0047198 A1 (ENGEL, BRADLEY, N. et al.) 03 March 2005 See figures 1,3; paragraphs [18],[20]	1-51



Further documents are listed in the continuation of Box C.



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